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#### **DESCRIPTION**

The RTC6671 power amplifier (PA) is designed to operate in 5GHz ISM band, compatible with 802.11a wireless LAN system with high power, high gain. The Amplifier consists of 3 gain stages with inter-stage matching, build-in input matching network, and a power detector for close loop power control operation. In 802.11a mode (OFDM 64QAM, 54Mbps), it provides a low EVM (Error-Vector magnitude) of 3% at +18dBm linear output power. The device is packaged in a tiny industry-standard 16-lead surface mount package QFN16 3x3.

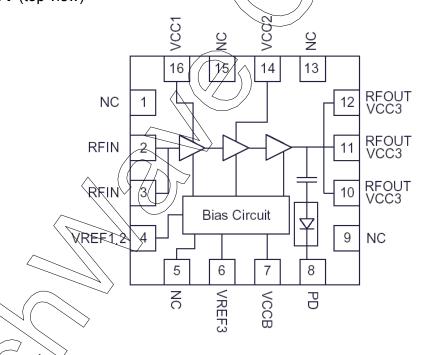
#### **FEATURE**

- ♦ 3.3V Power Supply
- ♦ Maximum Linear Output Power for 11a usage : +18 dBm ( 54Mbps OFDM 64 QAM )
- ♦ Small signal gain : 28dB
- ♦ On-chip input matching
- ♦ Operation ambient temperature: -40 ~ +85 °C
- ♦ Lead(Pb)-free, RoHS compliant packaging

#### **APPLICATION**

- ◆ IEEE 802.11a Wireless LAN System
- ♦ 5GHz ISM Band Application
- ◆ 5GHz Cordless Phones◆ High Power WLAN applications

# **PINOUT** (top view)





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## **PIN FUNCTION DESCRIPTION**

PIN	FUNCTION	DESCRIPTION
1,5,9,13,15	NC	Not connected
2	RFIN	RF input. Input matching network is built on chip.
3	RFIN	Same as pin 2
4	VREF1,2	Bias Control voltage of power stage-1 and stage-2, via R1 to 2.9V. Pin 4,6 can be used to control PA on/off.
6	VREF3	Bias Control voltage of power stage-3, via R2 to 2.9V. Pin 4,6 can be used to control PA on/off.
7	VCCB	Power supply for bias circuit, typically 3.3V
8	PD	Detector output voltage for output power index
10,11,12	RFOUT/VCC3	RF output. Power supply for power stage-3, typically 3.3V
14	VCC2	Power supply for power stage-2, typically 3.3V
16	VCC1	Power supply for power stage-1, typically 3.3V

# **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	RATING	UNITS
Supply Voltage	-0.5 to +5.0	V
Reference Voltage(Vref)	0.0 to +4.0	V
Input RF Level	+5	dBm
Operating Ambient Temperature	-40 to +85	$^{\circ}$ C
Storage Temperature	-40 to +150	$^{\circ}$

**\*Caution!** ESD Sensitive Device



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## DC ELECTRICAL CHRACTERISTICS

T=25°C, Vcc=3.3V

				/	
PARAMETER	CONDITION	MIN	TYP	MAX	UNITS
Supply Voltages					,
VCC1		3.0	3.3	4.2	Volts
VCC2		3.0	3.3	4.2	Volts
VCC3		3.0	3.3	4,2	Volts
VREF1,2	R1=0 ohm		2.9	<b>)</b>	Volts
VREF3	R2 =0 ohm		2.9		Volts
Supply Currents		4			
lcc1 + lcc2 + lcc3 (for 802.11A usage)	Quiescent (no RF) Pout= 18 dBm		105 160		mA
loff	Standby current		0.05		uA
Iref1,2	Quiescent (no/RF)		1.2		mA
Iref3	Quiescent (no RF)		1.2		mA

## **POWER DETECTOR**

T=25°C, Vcc=3.3V, Freq=5.4GHz, Vref=2\9\

PARAMETER	CONDITION	MIN	TYP	MAX	UNITS
Vpd	Power detector voltage  @ Pout=no RF		0.73		Volts
Vpd	Power detector voltage Pout=12 dBm		1.02		Volts
Vpd	Power detector voltage  @ Pout=15 dBm		1.20		Volts
Vpd	Power detector voltage  @ Pout=18 dBm		1.45		Volts
PD Resolution	PD Slope @Pout=15dBm		70		mV/dB

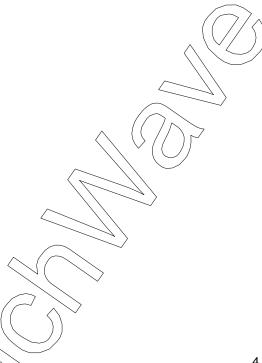


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## AC ELECTRICAL CHRACTERISTICS

T=25°C, Vcc=3.3V, Freq=5.4GHz

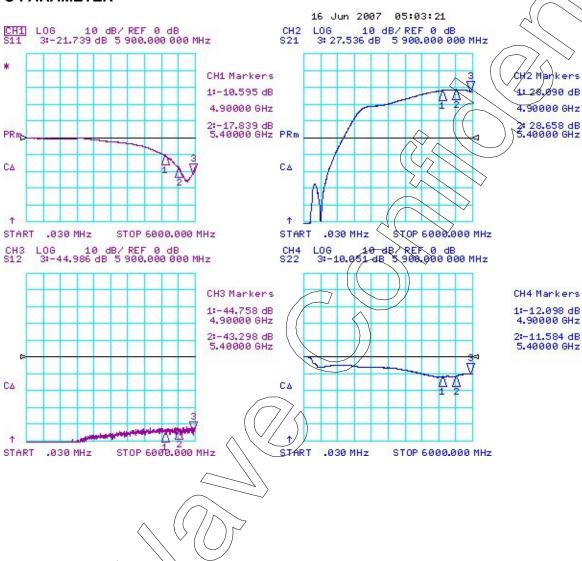
			/	
CONDITION	MIN	TYP	MAX	UNITS
	4.9	5.4	5.9	GHz
Measured @ P1dB		33:5		)) %
Pin= -20dBm	27.5	28	28.6	dB
1dB Gain compression	<u> </u>	26		dBm
802.11a OFDM 64 QAM EVM = 3%		18	·	dBm
802.11a OFDM 64 QAM		22		dBm
within band		\$2		dB
		> -10		dB
		-10		dB
CW signal, Pout = 18 dBm			-40	dBc
Rise time for 10% to 90% Pout		<100		ns
	Measured @ P1dB  Pin= -20dBm  1dB Gain compression  802.11a OFDM 64 QAM EVM = 3%  802.11a OFDM 64 QAM within band  CW signal, Pout = 18 dBm	Measured @ P1dB  Pin= -20dBm 27.5  1dB Gain compression  802.11a OFDM 64 QAM EVM = 3%  802.11a OFDM 64 QAM within band  CW signal, Pout = 18 dBm	4.9 5.4  Measured @ P1dB 33:5  Pin= -20dBm 27.5 28  1dB Gain compression 26  802.11a OFDM 64 QAM EVM = 3% 18  802.11a OFDM 64 QAM within band	4.9       5.4       5.9         Measured @ P1dB       33:5       28         Pin= -20dBm       27.5       28       28.6         1dB Gain compression       26       802.11a OFDM 64 QAM       18       18         802.11a OFDM 64 QAM       22       22       22       24       24         within band       ★2       -10       -10       -40         CW signal, Pout = 18 dBm       -40       -40





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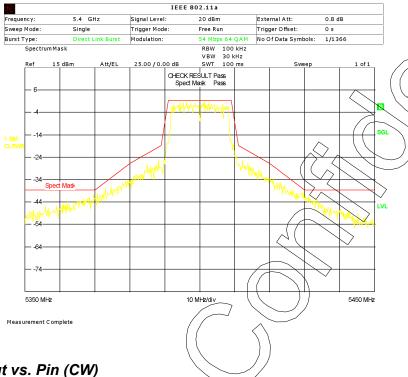
#### S-PARAMETER



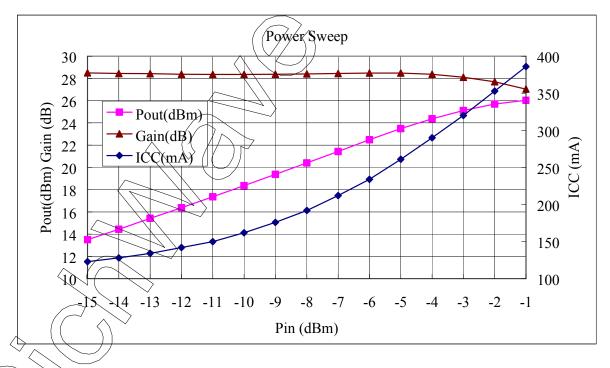


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# 802.11a Spectral Mask (54Mbps OFDM) at Pout = 22 dBm



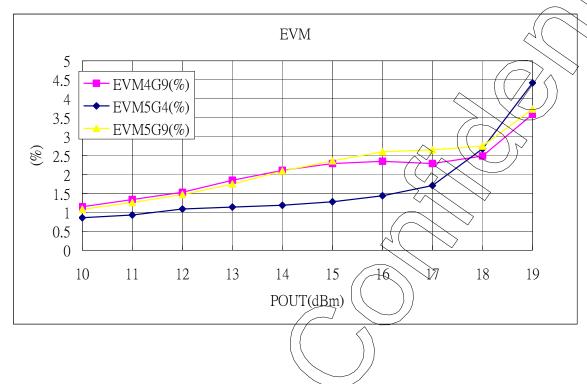
# Gain and Pout vs. Pin (CW)

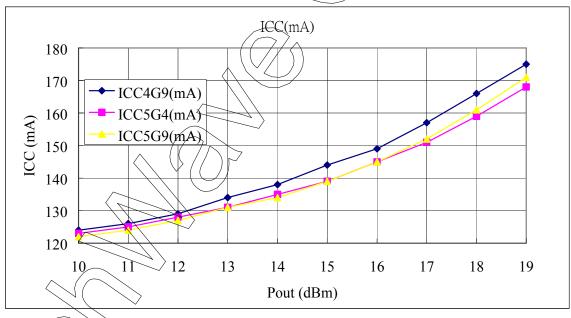




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# EVM and ICC vs. Pout(OFDM)



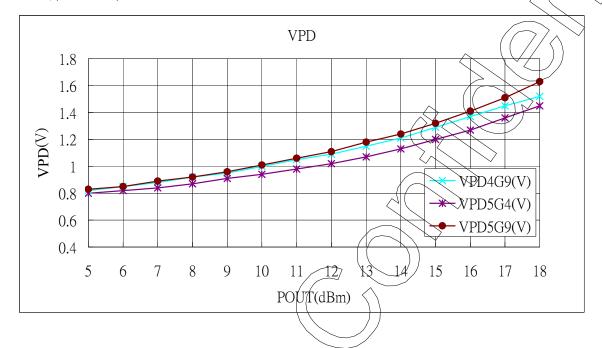




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## **POWER DETECTOR**

T=25 $^{\circ}$ C , Vcc=3.3V, Vref=2.9V

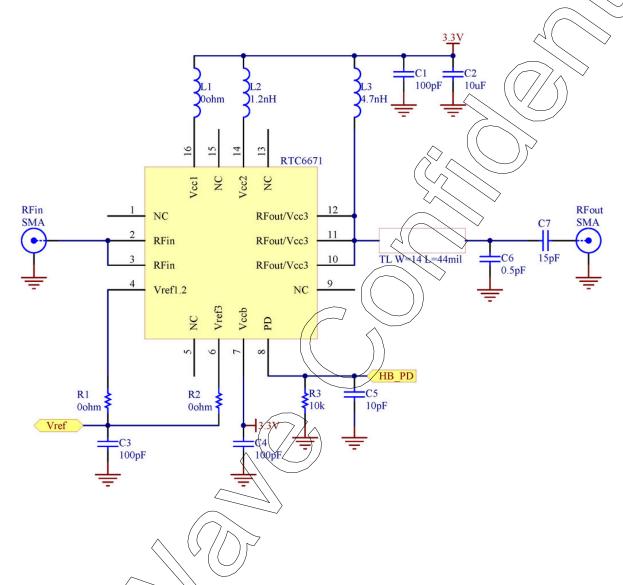






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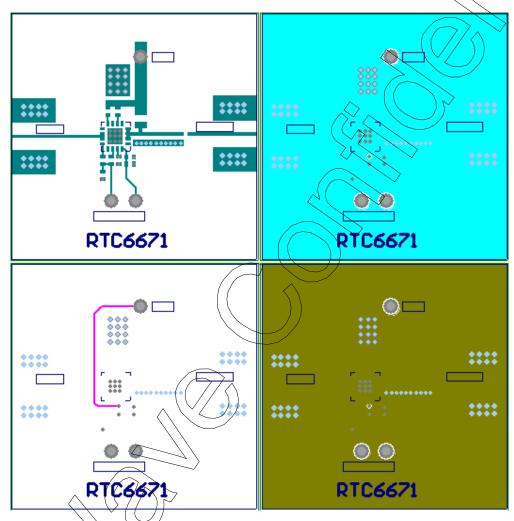
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#### **EVB LAYOUT:**

Top Layer MidLayer1 MidLayer2 Bottom Layer



Note: 1. VCC1, VCC2, VCC3 and VCCB are connected together and applied to 3.3V. VREF1, 2 and VREF3 can be connected together and applied to the other 2.9V.

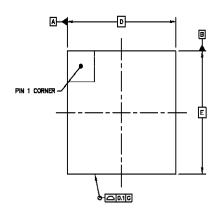
2. The evaluation board is 4-layer PCB using FR4 material. The thickness between top layer and MidLayer1 layer (GND) is 8 mil. If the PCB thickness is changed,  $50\,\Omega$  transmission line dimension needs to be re-calculated.

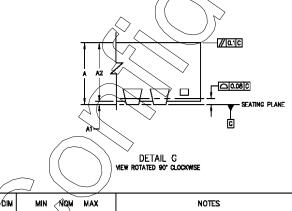


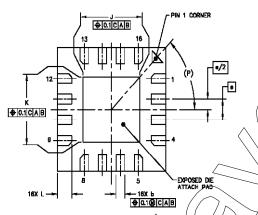
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# Package

Quad Flat No-Lead Plastic Package (QFN16 3x3)







,	$L_{-}$	$\sim$	
/	MID	MIN NOM MAX	NOTES
	A	0.85 0.95 1	1.0 COPLANARITY APPLIES TO LEADS, CORNER LEADS AND DIE ATTACH PAD.
/	X1	0 ø.0,35 0.05	AND DE ATTACH PAD.
	A2	0.85 0.9 0.95	
	b	0.2 0.25 0.3	
	ם	3 BSC	
	Ε	3 BSC	
>	, 8	0.5 BSC	
<	(4)	1.47 1.57 1.67	
	) ⋈	1.47 1.57 1.67	
/	$ \mathcal{L} $	0.35 0.4 0.45	
_	P	45' REF	